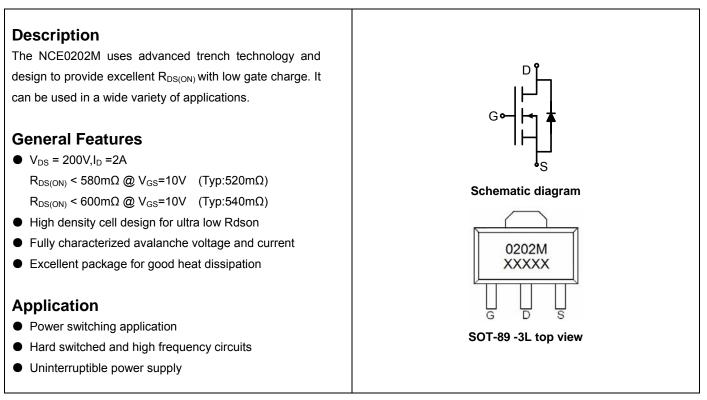


NCE N-Channel Enhancement Mode Power MOSFET



Package Marking and Ordering Information

	<u> </u>	<u> </u>			
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
0202M	NCE0202M	SOT-89-3L	Ø330mm	12mm	2500 units

Absolute Maximum Ratings (T_A=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	Vds	200	V	
Gate-Source Voltage	Vgs	±20	V	
Drain Current-Continuous	I _D	2	A	
Drain Current-Pulsed (Note 1)	I _{DM}	8	A	
Maximum Power Dissipation	PD	1.5	W	
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 150	°C	

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient ^(Note 2) R _{0JA} 83.3 °C/W			
	Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ extsf{ heta}JA}$	°C/W

Electrical Characteristics (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	200	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =200V,V _{GS} =0V	-	-	1	μA



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NCE0202M

Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	_	-	±100	nA
On Characteristics ^(Note 3)						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250µA	1.2	1.8	2.5	V
Davia October Devictores	R _{DS(ON)}	V _{GS} =10V, I _D =2A	-	520	580	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =2A	-	540	600	mΩ
Forward Transconductance	G FS	V _{DS} =15V,I _D =2A	-	8	-	S
Dynamic Characteristics (Note4)	·			•		
Input Capacitance	C _{lss}		-	580	-	PF
Output Capacitance	Coss	V _{DS} =25V,V _{GS} =0V, F=1.0MHz	-	90	-	PF
Reverse Transfer Capacitance	Crss		-	3	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	10	-	nS
Turn-on Rise Time	tr	V_{DD} =100V, R _L =15 Ω	-	12	-	nS
Turn-Off Delay Time	t _{d(off)}	V _{GS} =10V,R _G =2.5Ω	-	15	-	nS
Turn-Off Fall Time	t _f		-	15	-	nS
Total Gate Charge	Qg)/ -100)// -24	-	12		nC
Gate-Source Charge	Q _{gs}	V_{DS} =100V,I _D =2A,	-	2.5	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	3.8	-	nC
Drain-Source Diode Characteristics			·			-
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =2A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	2	А

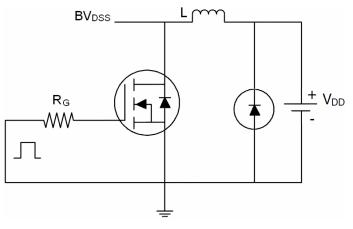
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production

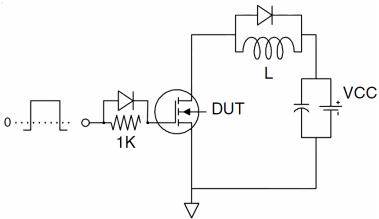


Test Circuit

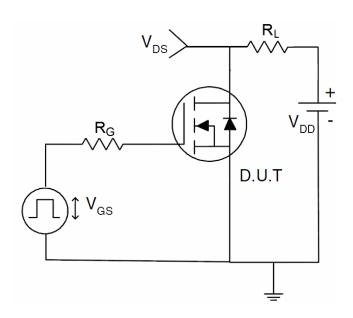
1) E_{AS} test circuit

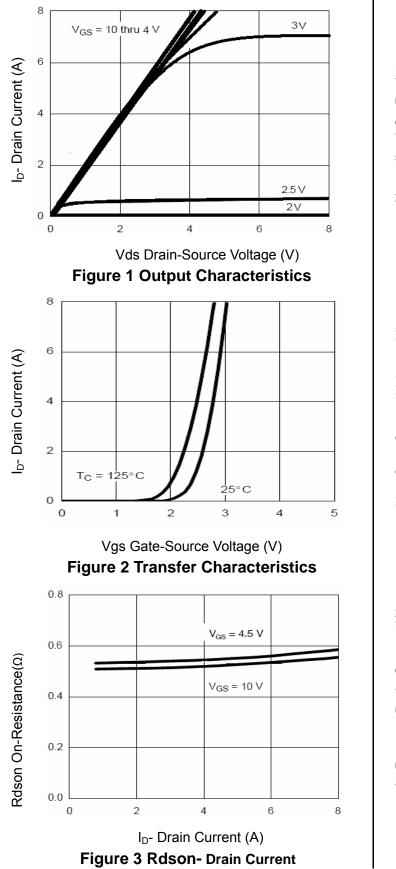


2) Gate charge test circuit



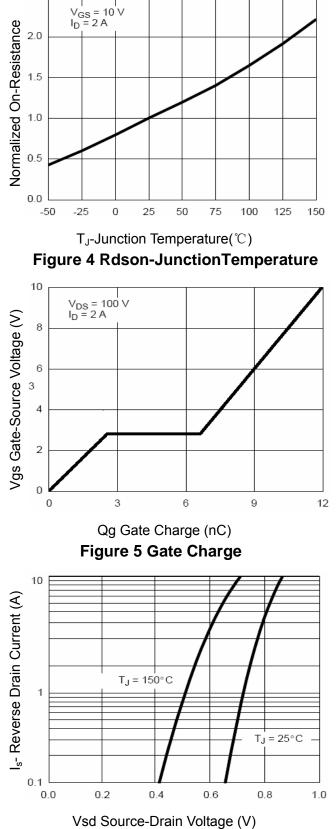
3) Switch Time Test Circuit



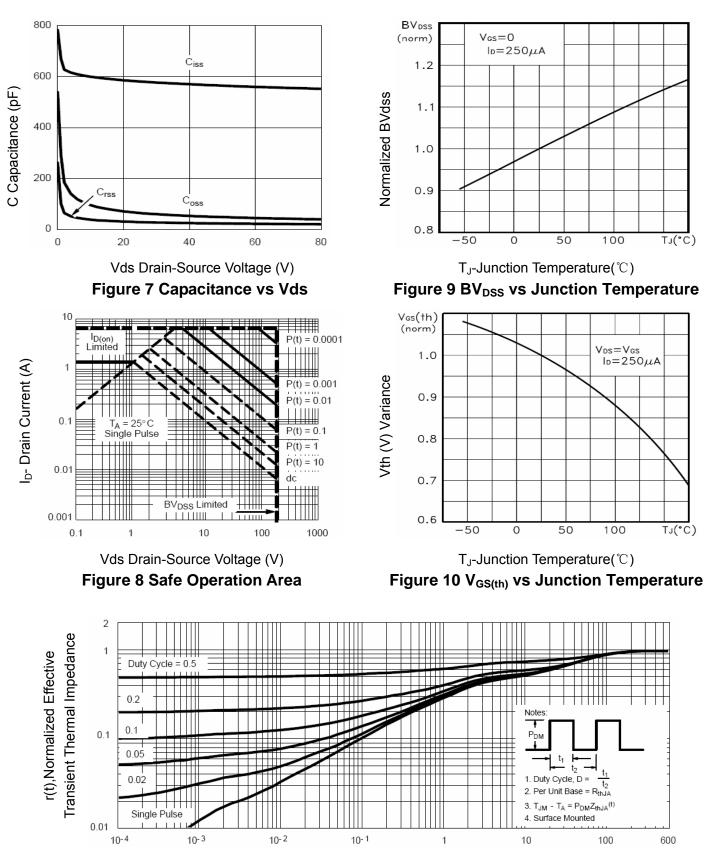


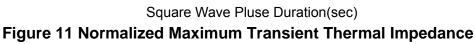
Typical Electrical and Thermal Characteristics (Curves)

2.5



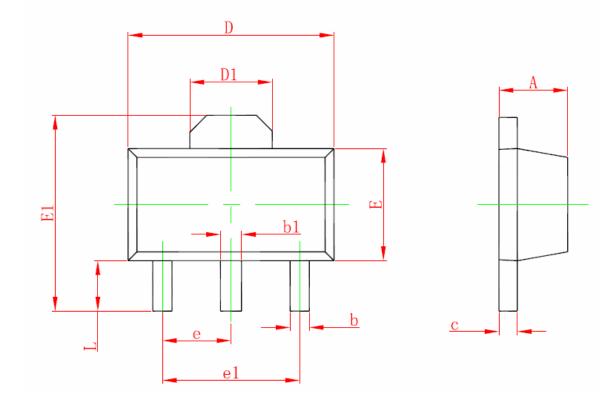








SOT-89-3L Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min	Max	Min	Мах	
A	1.400	1.600	0.055	0.063	
b	0.320	0.520	0.013	0.020	
b1	0.400	0.580	0.016	0.023	
с	0.350	0.440	0.014	0.017	
D	4.400	4.600	0.173	0.181	
D1	1.550	REF.	0.061 REF.		
E	2.300	2.600	0.091	0.102	
E1	3.940	4.250	0.155	0.167	
е	1.500	TYP.	0.060 TYP.		
e1	3.000 TYP.		0.118 TYP.		
L	0.900	1.200	0.035	0.047	

Notes

1. All dimensions are in millimeters.

2. Tolerance ±0.10mm (4 mil) unless otherwise specified

3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.

4. Dimension L is measured in gauge plane.

5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.



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